

#### RN2110,RN2111

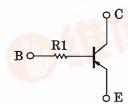
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

# RN2110,RN2111

## Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1110, RN1111

#### **Equivalent Circuit**

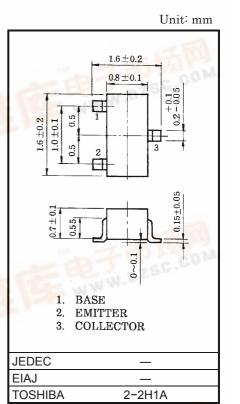


#### Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	Ι <sub>C</sub>	-100	mA
Collector power dissipation	PC	100	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

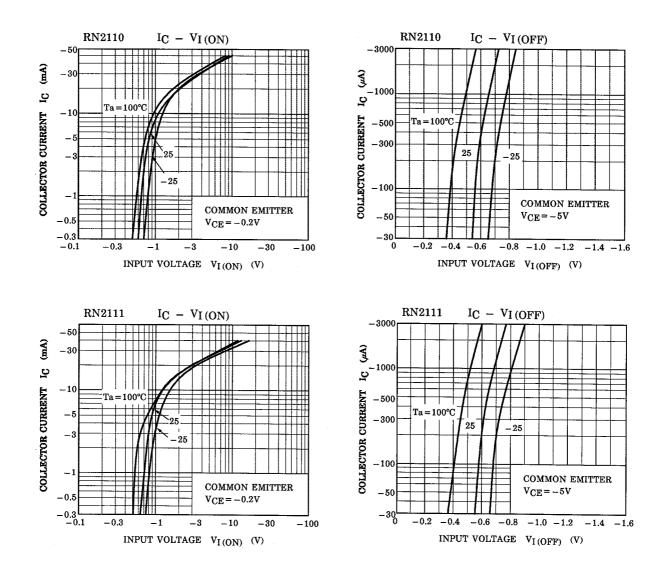
#### Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I <sub>CBO</sub>	_	$V_{CB} = -50V, I_E = 0$	_	-	-100	nA
Emitter cut-off current		I <sub>EBO</sub>	_	$V_{EB} = -5V, I_C = 0$	_	—	-100	nA
DC current gain		h <sub>FE</sub>	_	$V_{CE} = -5V, I_C = -1mA$	120	73	400	123
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	_	$I_{\rm C}$ = -5mA, $I_{\rm B}$ = -0.25mA	123	-0.1	-0.3	V
Transition frequency		f <sub>T</sub>	—	V <sub>CE</sub> = -10V, I <sub>C</sub> = -5mA	1	200		MHz
Collector output capacitance		C <sub>ob</sub>	_	V <sub>CB</sub> = -10V, I <sub>E</sub> = 0, f = 1MH <sub>z</sub>	_	3	6	pF
Input resistor	RN2110	R1	COM		3.29	4.7	6.11	kΩ
	RN2111				7	10	13	

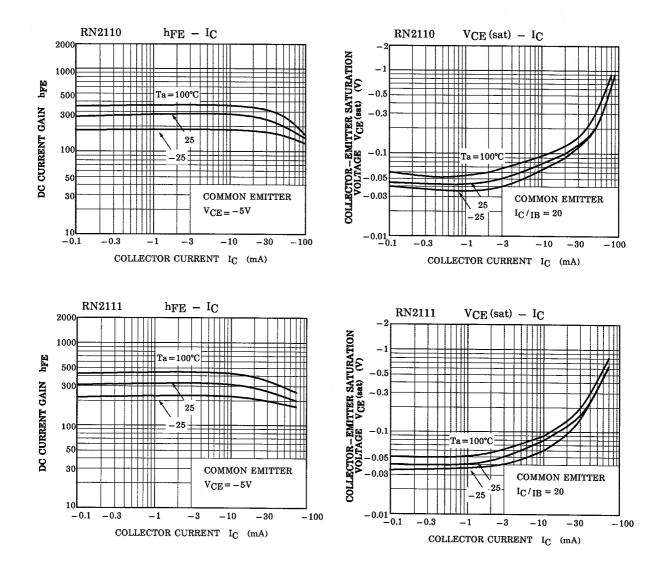


Weight: 2.4mg

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Type Name	Marking	
RN2110	Type Name <b>V</b> K <b>U</b> U	
RN2111	Type Name Y M H H	

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